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Vishay Semiconductors

RoHS

COMPLIANT

HALOGEN

FREE

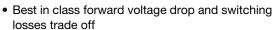
Hyperfast Rectifier, 30 A FRED Pt® G5

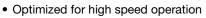


PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V_{R}	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	26 ns					
T _J max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

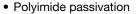
FEATURES

Hyperfast and optimized Q_{rr}





• 175 °C maximum operating junction temperature



 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V_{RRM}		1200	V				
Average rectified forward current	I _{F(AV)}	T _C = 105 °C, D = 0.50	30					
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	210	Α				
Repetitive peak forward current	I _{FRM}	T _C = 105 °C, D = 0.50, f = 20 kHz	60					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	$I_R = 100 \mu\text{A}$	1200	-	-			
Forward voltage	V _F	I _F = 30 A	-	2.6	3.15	V		
		I _F = 30 A, T _J = 125 °C	-	2.1	-			
Payaraa laakaga ayrrant	I _R	$V_R = V_R$ rated	-		50			
Reverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	500	μA		
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF		
Series inductance	LS	Measured to lead 5 mm from package body	-	8	-	nH		



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt = 10$	0 A/μs, V _R = 30 V	-	26	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns
		T _J = 125 °C		-	150	-	
Peak recovery current	1	T _J = 25 °C	$I_F = 20 \text{ A}$	-	12	-	А
	I _{RRM}	T _J = 125 °C	$dI_F/dt = 600 \text{ A/µs}$ $V_R = 400 \text{ V}$	-	22	-	
Davis and a second and a second	0	T _J = 25 °C		-	530	-	nC
Reverse recovery charge	Q_{rr}	T _J = 125 °C		-	1550	-	
Poverse receivery time		T _J = 25 °C		-	80	-	ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	120	-	
Dools recovery average		T _J = 25 °C	I _F = 30 A	-	22	-	^
Peak recovery current	IRRM	T _J = 125 °C	$dI_F/dt = 1000 A/\mu s$ $V_R = 800 V$	-	37	-	Α
Reverse recovery charge	0	T _J = 25 °C		-	900	-	nC
	Q _{rr}	T _J = 125 °C		-	2300	-	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.8	°C/W		
Weight			-	5.5	-	g		
Weight			-	0.2	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style: TO-247AD 2L	E5PX3012L					

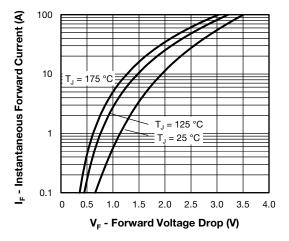


Fig. 1 - Typical Forward Voltage Drop Characteristics

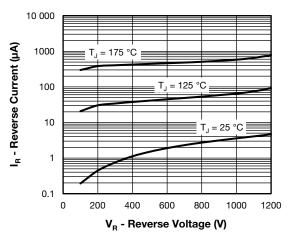


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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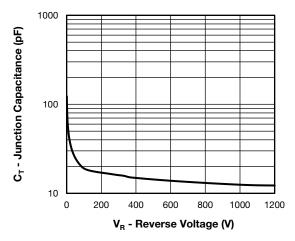


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

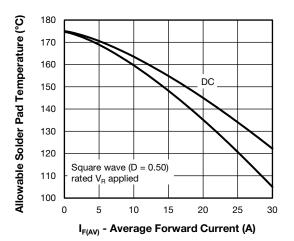


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

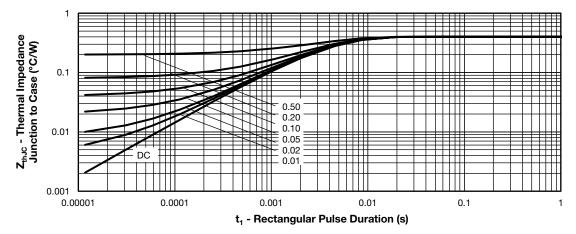


Fig. 5 - Thermal Impedance Z_{thJC} - Characteristics

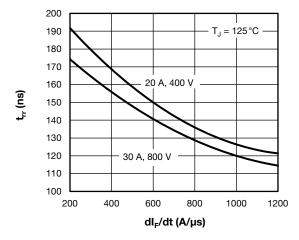


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

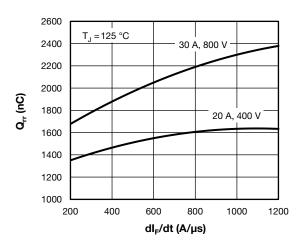


Fig. 7 - Typical Stored Charge vs. dl_F/dt

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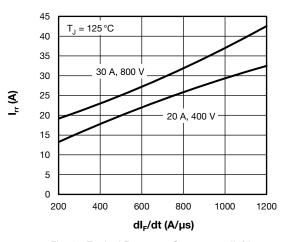


Fig. 8 - Typical Recovery Current vs. dl_F/dt

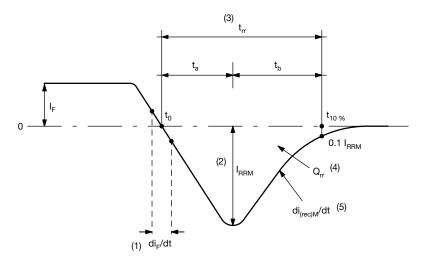


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ $\,Q_{rr}$ area under curve defined by t_0 and $t_{10}\,\%$

$$Q_{rr} = \int_{t_{a}}^{t_{10}\%} I(t)dt$$

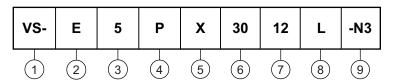
 $^{(5)}$ $di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

3 - 5 = Fred generation 5

4 - Package:

P = TO-247 package

- X = hyperfast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (12 = 1200 V)

Package: L = long lead (TO-247AD)

9 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-E5PX3012L-N3	25	500	Antistatic plastic tube				

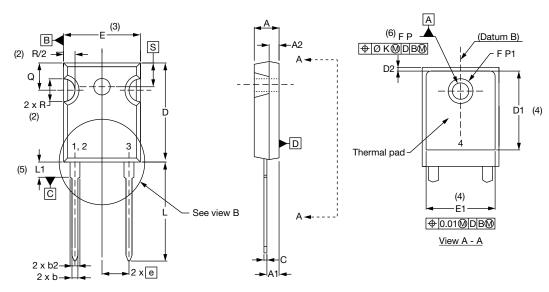
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95536					
Part marking information	www.vishay.com/doc?95648					
Spice model	www.vishay.com/doc?96684					

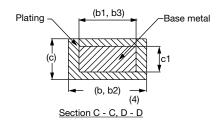


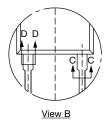
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TO-247AD 2L

DIMENSIONS in millimeters and inches







SYMBOL	MILLIN	IETERS	INC	NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIM	IETERS	INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	'BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077

85HFR60 40HFR60 1N1186RA 70HF120 85HFR80 D126A45C SCF7500 D251N08B SCHJ22.5K SM100 SCPA2 SCH10000 SDHD5K

VS-12FL100S10 ACGRA4001-HF D1821SH45T PR D1251S45T NTE5990 NTE6358